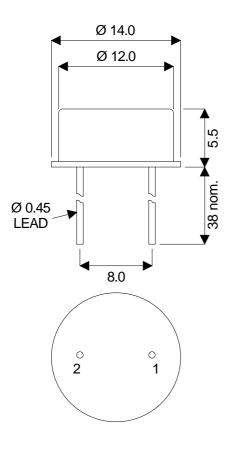
SMP690G-JQS



MECHANICAL DATA Dimensions in mm.



TO8 Small

Pin 1 – Anode

Pin 2 – Cathode & Case

P.I.N. PHOTODIODE

FEATURES

- HIGH SENSITIVITY
- EXCELLENT LINEARITY
- LOW NOISE
- WIDEST SPECTRAL RESPONSE
- ENHANCED UV SENSITIVITY
- INTEGRAL OPTICAL FILTER OPTION note 1
- TO8 HERMETIC METAL CAN PACKAGE
- EMI SCREENING MESH AVAILABLE

Note 1 Contact Semelab Plc for filter options

DESCRIPTION

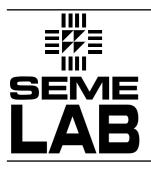
The SMP690G-JQS is a Silicon P.I.N. photodiode incorporated in a hermetic metal can package. The package window has greater ultra-violet light transmission, thus extending the useful spectral range of the device. The electrical terminations are via two leads of diameter 0.018" on pitch of 0.2". The cathode of the photodiode is electrically connected to the package.

The larger photodiode active area provides greater sensitivity than the SMP600 range of devices, with a corresponding reduction in speed. The photodiode structure has been optimised for high sensitivity, light measurement applications across the infra-red to ultraviolet spectrum. Inclusion of a suitable optical filter into the package can produce a device that responds only to ultraviolet light. The metal can and optional screening mesh ensure a rugged device with a high degree of immunity to radiated electrical interference.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

C	Dperating temperature range	-40°C to +70°C
S	Storage temperature range	-45°C to +80°C
Т	emperature coefficient of responsively	0.35% per °C
Т	emperature coefficient of dark current	x2 per 8°C rise
F	Reverse breakdown voltage	60V
		1

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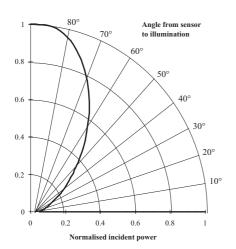


SMP690G-JQS

$\textbf{CHARACTERISTICS} (T_{amb} = 25^{\circ}\text{C unless otherwise stated})$

Characteristic	Test Conditions.		Min.	Тур.	Max.	Units
Responsively	λ at 900nm		0.45	0.55		A/W
Active Area				15		mm ²
Dark Current	E = 0 Dark	1V Reverse		2	6	nA
	E = 0 Dark	10V Reverse				
Breakdown Voltage	E = 0 Dark	10µA Reverse	60	80		V
Capacitance	E = 0 Dark	0V Reverse		90		pF
Capacitance	E = 0 Dark	20V Reverse		25		
Rise Time	30V Reverse			12		ns
	50Ω					
NEP	900nm			20x10 ⁻¹⁴	0.45	W/√Hz

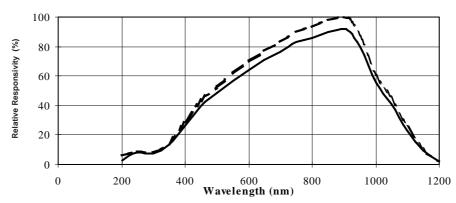
Directional characteristics



1 0.9 0.8 0.7 Normalised Incident Power 0.6 0.5 0.4 0.3 0.2 0.1 0 0 10 20 30 40 50 60 70 80 90 Angle from sensor to illumination

Directional Characteristics





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